



Single Phase Diode Bridge KBPC50, KBPC50-W



Key Parameters

I_o	=	50	A
V_{RRM}	=	50 - 1600	V
$V_R(RMS)$	=	35 - 1120	V
I_{FSM}	=	450	A
I^2t	=	800	$m\Omega$

Properties

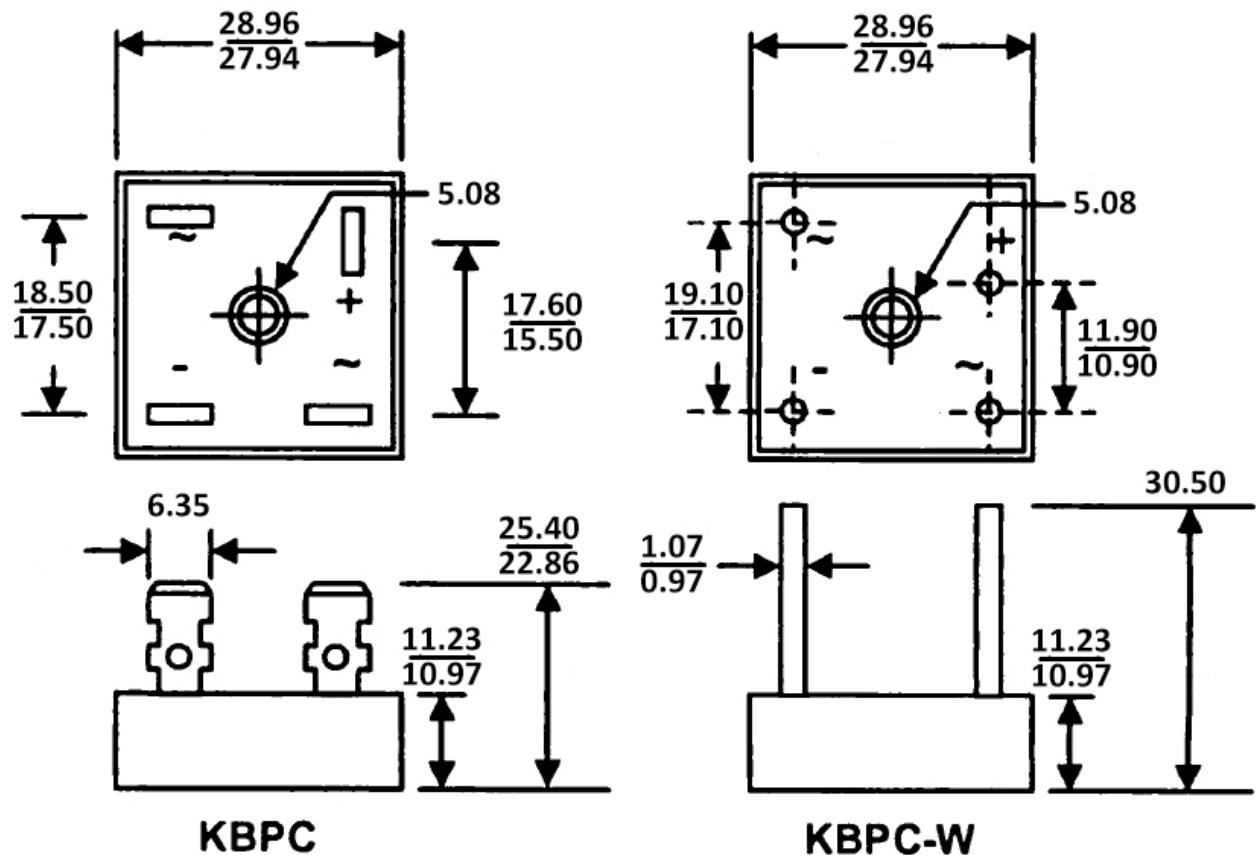
- Compact construction
- High surge current capability
- Low reverse leakage current
- Low power loss, high efficiency

*"W" in marking indicate case with wire leads

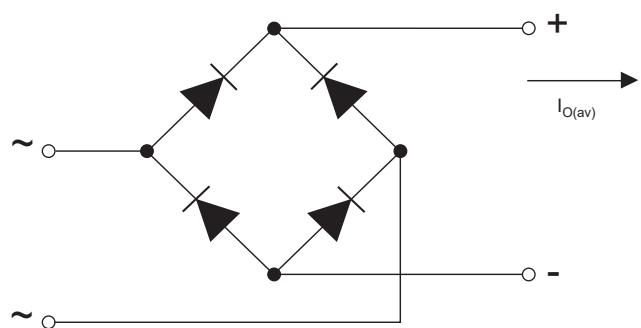
MAXIMUM ALLOWABLE RATINGS AND ELECTRICAL CHARACTERISTICS

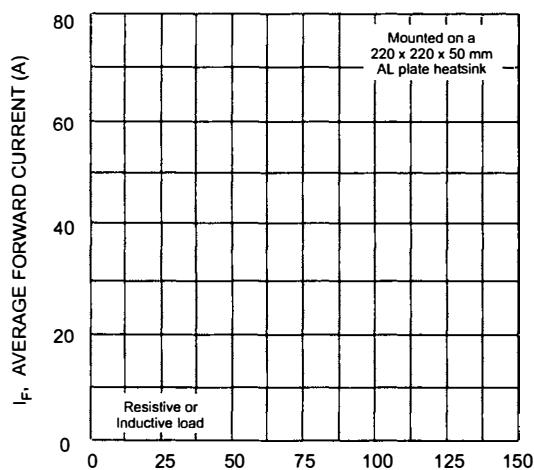
Symbols, parameters and values											Unit
V_{RRM}	Repetitive peak reverse voltage	50	100	200	400	600	800	1000	1200	1400	1600
$V_{R(RMS)}$	RMS reverse voltage	35	70	140	280	420	560	700	840	980	1120
I_o	Average rectified output current	$T_C = 60 \text{ }^\circ\text{C}$								15	A
I_{FSM}	Non repetitive peak forward surge current	$t_P = 8.3 \text{ ms}$ $T_C = 25 \text{ }^\circ\text{C}$								450	A
V_{FM}	Forward voltage per leg	$I_F = 25 \text{ A}$ $T_C = 25 \text{ }^\circ\text{C}$								1.2	V
I_{RM}	Peak reverse current At rated DC blocking Voltage	$T_C = 25 \text{ }^\circ\text{C}$ $T_C = 125 \text{ }^\circ\text{C}$								10 1.0	μA mA
I^2t	I^2t rating for fusing	$t_P = 8.3 \text{ ms}$ $T_C = 25 \text{ }^\circ\text{C}$								800	A^2s
C_j	Typical junction capacitance	$T_C = 25 \text{ }^\circ\text{C}$								300	pF
$R_{th(jc)}$	Typical thermal resistance per leg	$T_C = 25 \text{ }^\circ\text{C}$								1.6	$^\circ\text{C/W}$
V_{ISOL}	RMS isolation voltage from case to leads	$T_C = 25 \text{ }^\circ\text{C}$								2500	V
T_j, T_{STG}	Operation and storage temperature range									-65...+150	$^\circ\text{C}$

DIMENSIONS

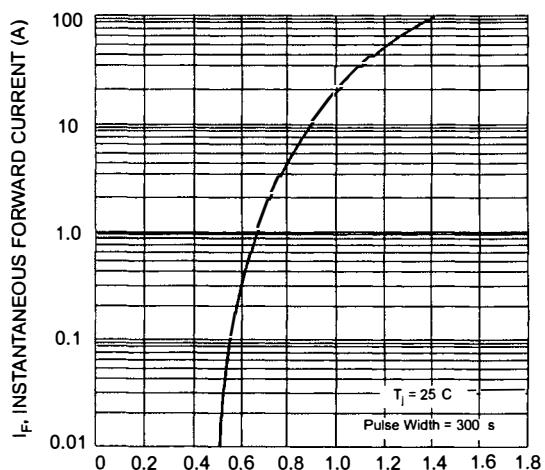


TOPOLOGY OF INTERNAL CONNECTION

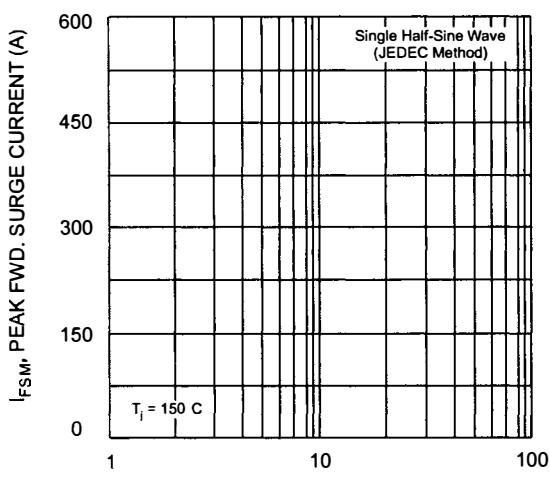




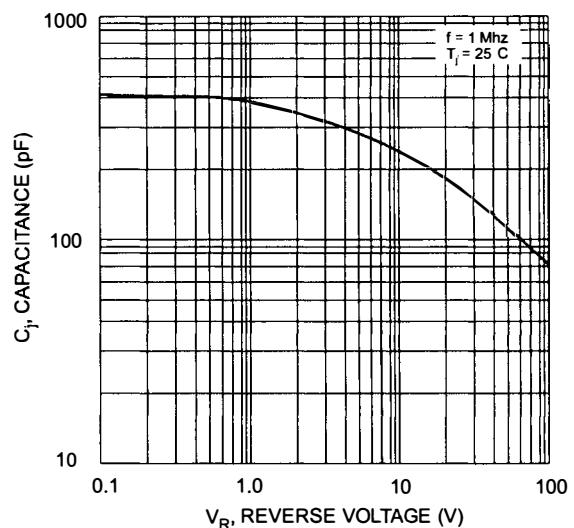
T_A , AMBIENT TEMPERATURE (C)
Fig. 1 Forward Current Derating Curve



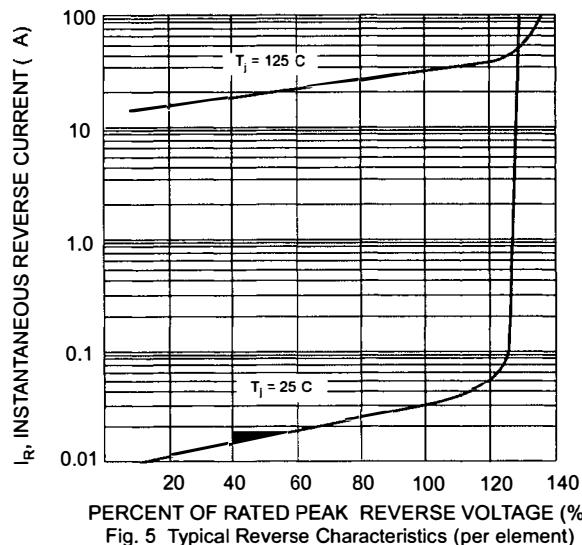
V_F , INSTANTANEOUS FORWARD VOLTAGE (V)
Fig. 2 Typical Forward Characteristics (per element)



I_{FSM} , PEAK FWD. SURGE CURRENT (A)
NUMBER OF CYCLES AT 60 Hz
Fig. 3 Max Non-Repetitive Surge Current



C_J , CAPACITANCE (pF)
 V_R , REVERSE VOLTAGE (V)
Fig. 4 Typical Junction Capacitance (per element)



I_R , INSTANTANEOUS REVERSE CURRENT (A)
PERCENT OF RATED PEAK REVERSE VOLTAGE (%)
Fig. 5 Typical Reverse Characteristics (per element)